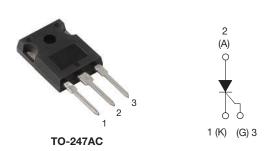
VS-40TPS16PbF, VS-40TPS16-M3

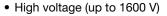
Vishay Semiconductors

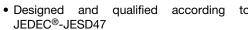
Thyristor High Voltage, Phase Control SCR, 40 A



| PRODUCT SUMMARY | | | | | | | | |
|------------------------------------|------------------|--|--|--|--|--|--|--|
| Package | TO-247AC | | | | | | | |
| Diode variation | Single SCR | | | | | | | |
| I _{T(AV)} | 35 A | | | | | | | |
| V _{DRM} /V _{RRM} | 1600 V | | | | | | | |
| V_{TM} | 1.45 V | | | | | | | |
| I _{GT} | 150 mA | | | | | | | |
| TJ | -40 °C to 125 °C | | | | | | | |

FEATURES







Material categorization:
 For definitions of compliance please see www.vishay.com/doc?99912







APPLICATIONS

 Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

DESCRIPTION

The VS-40TPS16... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | | | |
|------------------------------------|------------------------------|------------|-------|--|--|--|--|--|--|
| PARAMETER | TEST CONDITIONS | VALUES | UNITS | | | | | | |
| I _{T(AV)} | Sinusoidal waveform | 35 | А | | | | | | |
| I _{RMS} | | 55 | | | | | | | |
| V _{RRM} /V _{DRM} | | 1600 | V | | | | | | |
| I _{TSM} | | 500 | А | | | | | | |
| V _T | 40 A, T _J = 25 °C | 1.45 | V | | | | | | |
| dV/dt | | 1000 | V/µs | | | | | | |
| dl/dt | | 100 | A/µs | | | | | | |
| T _J | | -40 to 125 | °C | | | | | | |

| VOLTAGE RATINGS | | | | | | | | | | |
|------------------------------|---|---|---|--|--|--|--|--|--|--|
| PART NUMBER | V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I _{RRM} /I _{DRM} AT 125 °C mA | | | | | | | |
| VS-40TPS16PbF, VS-40TPS16-M3 | 1600 | 1700 | 10 | | | | | | | |



VS-40TPS16PbF, VS-40TPS16-M3

Vishay Semiconductors

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | |
|--|------------------------------------|---|---|-------|--------------------|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | | |
| Maximum average on-state current | I _{T(AV)} | $T_C = 79 ^{\circ}\text{C}$, 180° conduction half sine wave | 35 | | | | | |
| Maximum continuous RMS on-state current as AC switch | I _{T(RMS)} | | | 55 | Α | | | |
| Maximum peak, one-cycle | I _{TSM} | 10 ms sine pulse, rated V_{RRM} applied | | 420 | | | | |
| non-repetitive surge current | TISM | 10 ms sine pulse, no voltage reapplied | | 500 | | | | |
| Maximum I ² t for fusing | l ² t | 10 ms sine pulse, rated V _{RRM} applied | Initial $T_J = T_H$ maximum | 880 | - A ² s | | | |
| Waxiiiluiii i-t for fusiiig | I-t | 10 ms sine pulse, no voltage reapplied | . 0 | 1250 | | | | |
| Maximum I ² √t for fusing | I ² √t | t = 0.1 to 10 ms, no voltage reapplied | 12 500 | A²√s | | | | |
| Low level value of threshold voltage | V _{T(TO)1} | | | 1.02 | V | | | |
| High level value of threshold voltage | V _{T(TO)2} | T _J = 125 °C | 1.23 | V | | | | |
| Low level value of on-state slope resistance | r _{t1} | 1j = 125 C | | 9.74 | mΩ | | | |
| High level value of on-state slope resistance | r _{t2} | | | 7.50 | | | | |
| Maximum peak on-state voltage | V_{TM} | 110 A, T _J = 25 °C | | 1.85 | V | | | |
| Maximum rate of rise of turned-on current | dl/dt | T _J = 25 °C | | 100 | A/μs | | | |
| Maximum holding current | I _H | Anode supply = 6 V, resistive load, initial I_T | 200 | | | | | |
| Maximum latching current | ΙL | Anode supply = 6 V, resistive load, T _J = 25 | 300 | | | | | |
| Marian na n | | T _J = 25 °C | | 0.5 | mA | | | |
| Maximum reverse and direct leakage current | I _{RRM} /I _{DRM} | $T_J = 125 ^{\circ}\text{C}$ $V_R = \text{Rated } V_{RRM} / V_{DR}$ | V _R = Rated V _{RRM} /V _{DRM} | | | | | |
| Maximum rate of rise of off-state voltage | dV/dt | $T_J = T_J$ maximum, linear to 80 % V_{DRM} , $R_g - k = Open$ 1000 | | | | | | |

| TRIGGERING | | | | | |
|--|--------------------|---|-----------------------------------|------|---------|
| PARAMETER | SYMBOL | 1 | TEST CONDITIONS | | |
| Maximum peak gate power | P_{GM} | | | | |
| Maximum average gate power | P _{G(AV)} | | | 2.5 | W |
| Maximum peak gate current | I _{GM} | | | 2.5 | Α |
| Maximum peak negative gate voltage | - V _{GM} | | | 10 | |
| Maximum required DC gate voltage to trigger | | T _J = - 40 °C | | 4.0 | V mA |
| | V_{GT} | T _J = 25 °C | Anode supply = 6 V resistive load | 2.5 | |
| voltage to trigger | | T _J = 125 °C | | 1.7 | |
| | | T _J = - 40 °C | | 270 | |
| Maximum required DC gate augreent to trigger | l _{GT} | T _J = 25 °C | Anode supply = 6 V resistive load | 150 | |
| Maximum required DC gate current to trigger | | T _J = 125 °C | | 80 | |
| | | T _J = 25 °C, for 40 | 40 | | |
| Maximum DC gate voltage not to trigger | V_{GD} | T _J = 125 °C, V _{DRM} = Rated value | | 0.25 | V |
| Maximum DC gate current not to trigger | I_{GD} | | | 6 | mA |



| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | | | | | |
|---|---------|------------------------|--------------------------------------|------------|------------|--|--|--|--|
| PARAMETER | | SYMBOL TEST CONDITIONS | | VALUES | UNITS | | | | |
| Maximum junction and storage temperature range | | T_J, T_Stg | | -40 to 125 | °C | | | | |
| Maximum thermal resistance, junction to case | | R_{thJC} | DC operation | 0.6 | | | | | |
| Maximum thermal resistance, junction to ambient | | R _{thJA} | | 40 | °C/W | | | | |
| Maximum thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, smooth and greased | 0.2 | | | | | |
| Approximate weight | | | | 6 | g | | | | |
| Approximate weight | | | | 0.21 | OZ. | | | | |
| Mounting torque | minimum | | | 6 (5) | kgf ⋅ cm | | | | |
| Wounting torque | maximum | | | 12 (10) | (lbf · in) | | | | |
| Marking device | | | Case style TO-247AC | 40TF | PS16 | | | | |

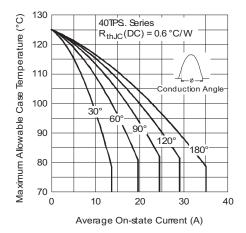


Fig. 1 - Current Rating Characteristics

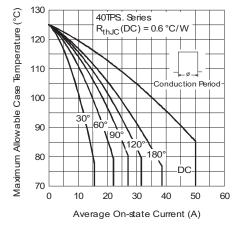


Fig. 2 - Current Rating Characteristics

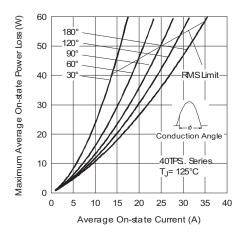


Fig. 3 - On-State Power Loss Characteristics

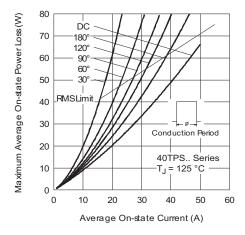


Fig. 4 - On-State Power Loss Characteristics

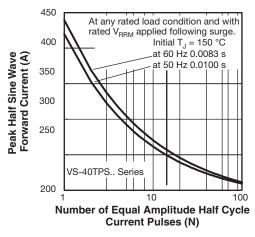


Fig. 5 - Maximum Non-Repetitive Surge Current

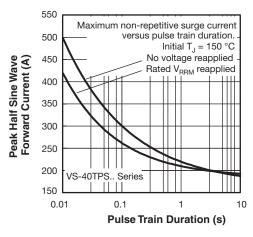


Fig. 6 - Maximum Non-Repetitive Surge Current

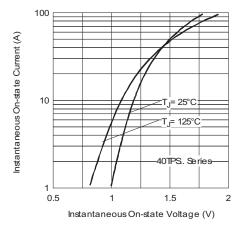


Fig. 7 - On-State Voltage Drop Characteristics

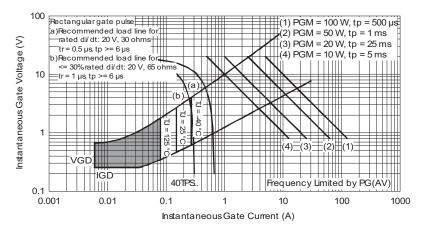


Fig. 8 - Gate Characteristics

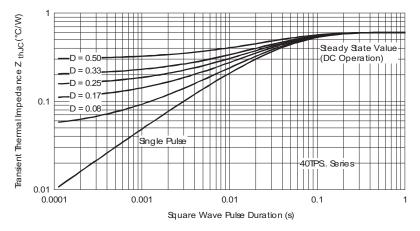
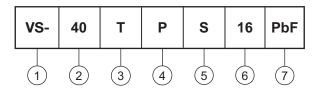


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (40 = 40 A)

- Circuit configuration:

T = Thyristor

Package:

P = TO-247

5 - Type of silicon:

S = Standard recovery rectifier

6 - Voltage rating (16 = 1600 V)

7 - Environmental digit:

PbF = Lead (Pb)-free and RoHS compliant

-M3 = Halogen-free, RoHS compliant, and terminations lead (Pb)-free

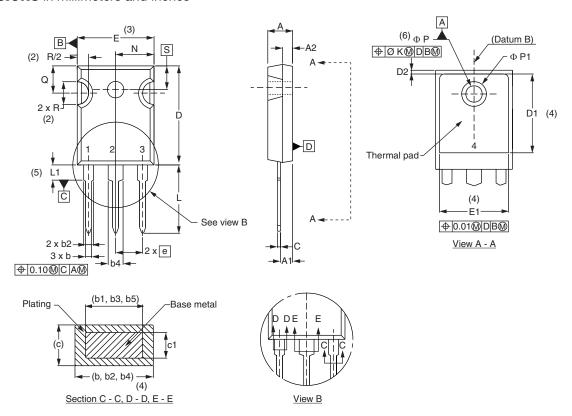
| ORDERING INFORMATION (Example) | | | | | | | | | |
|--------------------------------|------------------|------------------------|--------------------------|--|--|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | | | |
| VS-40TPS16PbF | 25 | 500 | Antistatic plastic tubes | | | | | | |
| VS-40TPS16-M3 | 25 | 500 | Antistatic plastic tubes | | | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | | |
|-------------------------------------|--------------|--------------------------|--|--|--|--|
| Dimensions www.vishay.com/doc?95542 | | | | | | |
| Part marking information | TO-247AC PbF | www.vishay.com/doc?95226 | | | | |
| | TO-247AC -M3 | www.vishay.com/doc?95007 | | | | |



TO-247 - 50 mils L/F

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIN | MILLIMETERS | | INCHES | | NOTES | SYMBOL | MILLIMETERS | | INCHES | | NOTES |
|--------|--------|-------------|-------|--------|-------|-------|---------|-------------|-------|--------|-------|-------|
| STMBOL | MIN. | MAX. | MIN. | MAX. | NOTES | | STWIBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| Α | 4.65 | 5.31 | 0.183 | 0.209 | | | D2 | 0.51 | 1.35 | 0.020 | 0.053 | |
| A1 | 2.21 | 2.59 | 0.087 | 0.102 | | | E | 15.29 | 15.87 | 0.602 | 0.625 | 3 |
| A2 | 1.17 | 1.37 | 0.046 | 0.054 | | | E1 | 13.46 | - | 0.53 | - | |
| b | 0.99 | 1.40 | 0.039 | 0.055 | | | е | 5.46 | BSC | 0.215 | BSC | |
| b1 | 0.99 | 1.35 | 0.039 | 0.053 | | | ØΚ | 0.2 | 254 | 0.0 |)10 | |
| b2 | 1.65 | 2.39 | 0.065 | 0.094 | | | L | 14.20 | 16.10 | 0.559 | 0.634 | |
| b3 | 1.65 | 2.34 | 0.065 | 0.092 | | | L1 | 3.71 | 4.29 | 0.146 | 0.169 | |
| b4 | 2.59 | 3.43 | 0.102 | 0.135 | | | Ν | 7.62 | BSC | 0 | .3 | |
| b5 | 2.59 | 3.38 | 0.102 | 0.133 | | | ØΡ | 3.56 | 3.66 | 0.14 | 0.144 | |
| С | 0.38 | 0.89 | 0.015 | 0.035 | | | Ø P1 | - | 7.39 | - | 0.291 | |
| c1 | 0.38 | 0.84 | 0.015 | 0.033 | | | Q | 5.31 | 5.69 | 0.209 | 0.224 | |
| D | 19.71 | 20.70 | 0.776 | 0.815 | 3 | | R | 4.52 | 5.49 | 0.178 | 0.216 | |
| D1 | 13.08 | - | 0.515 | - | 4 | | S | 5.51 | BSC | 0.217 | 'BSC | |

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- $^{(7)}$ Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q



Legal Disclaimer Notice

Vishay

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Revision: 13-Jun-16 1 Document Number: 91000

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T2160N28TOF VT TT251N16KOF-K VS-22RIA100 VS-16RIA40 TD250N16KOF-A VS-ST110S16P0 T930N36TOF VT T2160N24TOF

VT T1190N18TOF VT T1590N28TOF VT 2N1776A T590N14TOF NTE5375 NTE5460 NTE5481 NTE5512 NTE5514 NTE5518

NTE5519 NTE5529 NTE5553 NTE5555 NTE5557 NTE5567 NTE5570 NTE5570 NTE5574 NTE5576 NTE5579 NTE5589 NTE5592

NTE5598